

60V NPN ULTRA-LOW VCE(sat) TRANSISTOR IN PowerDI3333-8

Features

- BVcEo > 60V
- BVEBO > 8V
- Continuous Current Ic to 6.5A
- Peak Pulse Current Icm to 15A
- Ultra-Low Saturation Voltage V_{CE(sat)} < 40mV @ 1A
- High Current R_{CE(sat)} = 16mΩ Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to +175°C Ideal for High-Temperature Environments
- Complementary PNP Type: <u>DXTP80060DFGQ</u>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN80060DFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

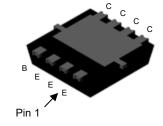
- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

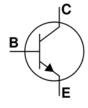
Applications

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulation
- DC to DC converters
- Motors, solenoids, relays and actuator drivers control

PowerDI3333-8/SWP (Type UX)







Top View

Bottom View

Device Symbol

Ordering Information (Note 4)

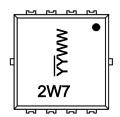
Orderable Part Number	Package	Marking	Reel Size (inches) Tape Width (mm)		Pac	acking	
Orderable Part Number	Package	Warking	Reel Size (Iliches)	rape width (min)	Qty.	Carrier	
DXTN80060DFGQ-7	PowerDI3333-8/SWP (Type UX)	2W7	7	12	2,000	Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8/SWP (Type UX)



2W7 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 25 = 2025)
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	100	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	V _{EBO}	8	V
Continuous Collector Current (Note 5)	Ic	4	Α
Continuous Collector Current (Note 7)	Ic	6.5	Α
Peak Pulse Current	Ісм	15	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		900	mW
Power Dissipation	(Note 6)	PD	1.6	W
	(Note 7)		2.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	92	°C/W
	(Note 7)		62.5	°C/W
Thermal Resistance, Junction to Case (Note 7)	Rejc	6.5	°C/W	
Thermal Resistance, Junction to Lead (Note 8)		Rejl	4.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

Notes:

- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.
- 6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specifications JESD22-A114, JESD22-A115 and JESD22-C101.



Thermal Characteristics and Derating Information

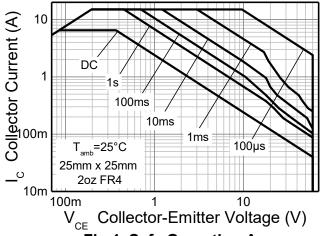


Fig 1. Safe Operating Area

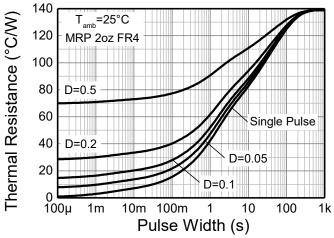


Fig 2. Transient Thermal Impedance

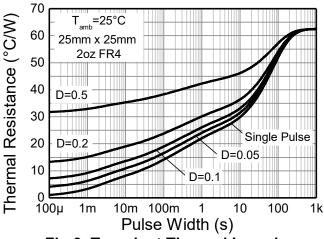


Fig 3. Transient Thermal Impedance

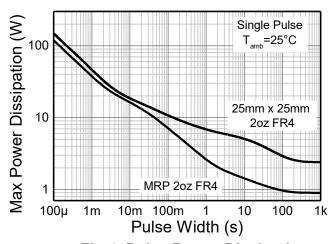


Fig 4. Pulse Power Dissipation

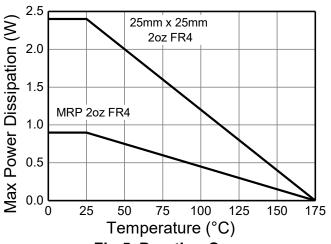


Fig 5. Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	100	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BVceo	60	_	_	V	I _C = 10mA
Emitter-Collector Breakdown Voltage	BVECO	5	_	_	V	I _E = 100μA
Emitter-Base Breakdown Voltage	ВУево	8	_	_	V	I _E = 100μA
Collector Cutoff Current	Ісво	_	_	100	nA	V _{CB} = 100V
Collector Cutoff Current		_	_	10	μΑ	V _{CB} = 100V, T _A = +125°C
Collector Cutoff Current	Ices	_	_	300	nA	V _{CE} = 48V
Emitter Cutoff Current	I _{EBO}	_	_	50	nA	V _{EB} = 7V
		_	50	_	mV	I _C = 100mA, I _B = 1mA
		_	45	80	mV	I _C = 1A, I _B = 20mA
Collector-Emitter Saturation Voltage (Note 10)	V	_	22	40	mV	I _C = 1A, I _B = 100mA
Collector-Enfilter Saturation voltage (Note 10)	V _{CE(sat)}	_	70	120	mV	I _C = 2A, I _B = 40mA
		_	75	130	mV	I _C = 4A, I _B = 200mA
		_	100	200	mV	I _C = 6.5A, I _B = 650mA
Page Emitter Seturation Voltage (Note 10)		_	880	1,000	mV	I _C = 4A, I _B = 200mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	_	980	1,100	mV	I _C = 6.5A, I _B = 650mA
Page Emitter Turn On Voltage (Note 10)	VBE(on)	_	750	850	mV	I _C = 4A, V _{CE} = 2V
Base-Emitter Turn-On Voltage (Note 10)		_	800	950	mV	Ic = 6.5A, VcE = 2V
		250	370	_	-	I _C = 10mA, V _{CE} = 2V
		300	370	550	-	Ic = 100mA, VcE = 2V
DC Current Gain (Note 10)		260	350	_	-	Ic = 1A, VcE = 2V
DC Current Gain (Note 10)	hfE	250	335	_	_	I _C = 2A, V _{CE} = 2V
		140	250	_	_	I _C = 4A, V _{CE} = 2V
		35	110	_	_	I _C = 6.5A, V _{CE} = 2V
Input Capacitance	Cibo	_	620	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	_	30	_	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f⊤	100	140	_	MHz	V _{CE} = 10V, I _C = 100mA f = 50MHz
Turn-On Time	td	_	14	_	ns	
	tr	_	80	_	ns	$V_{CC} = 10V, I_C = 4A$
Turn-Off Time	ts	_	375	_	ns	$I_{B1} = -I_{B2} = 400 \text{mA}$
	tf	_	28	_	ns	

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300\mu s$. Duty cycle $\leq 2\%$.

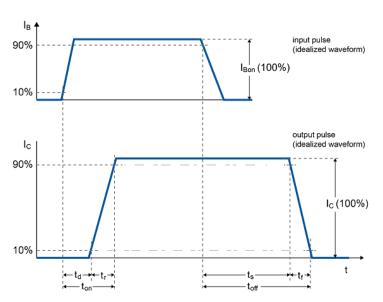
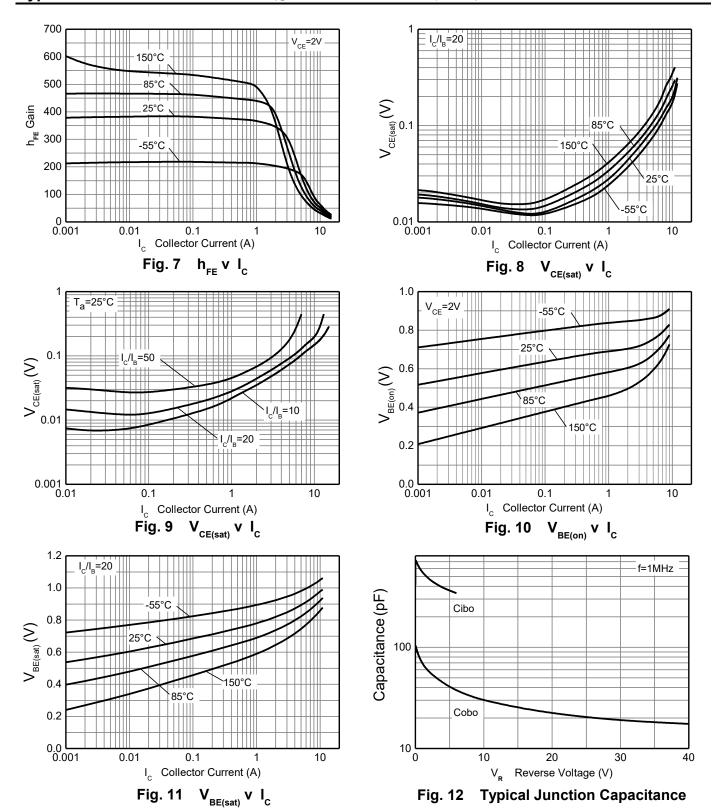


Fig 6. Timing Waveform



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Typical Electrical Characteristics (continued) (@TA = +25°C, unless otherwise specified.)

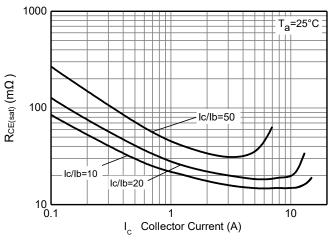


Fig. 13 $R_{CE(sat)} v I_{C}$

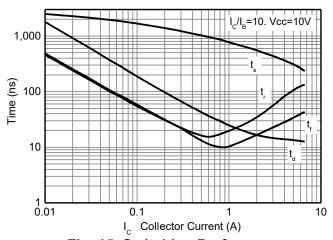


Fig. 15 Switching Performance

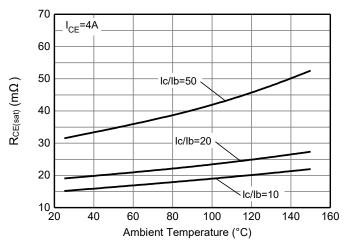


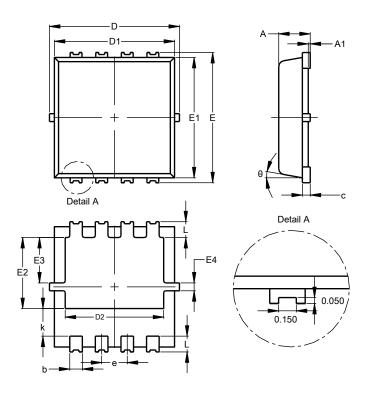
Fig. 14 $R_{CE(sat)} v T_{amb}$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)

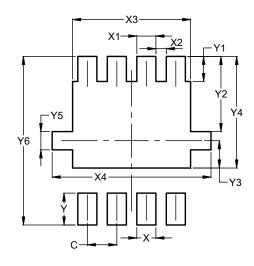


PowerDI3333-8/SWP						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: 11. Side wall tin plated package for wettable flanks in AOI.



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